MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Power Dissipation (Note 1) @ T_L = 25°C, Pulse Width = 1 ms	P _{PK}	400	W
DC Power Dissipation @ T _L = 75°C Measured Zero Lead Length (Note 2)	P _D	1.5	W
Derate Above 75°C		20	mW/°C
Thermal Resistance from Junction to Lead	$R_{ ext{ heta}JL}$	50	°C/W
DC Power Dissipation (Note 3) @ $T_A = 25^{\circ}C$ Derate Above 25°C	PD	0.5 4.0	W mW/°C
Thermal Resistance from Junction to Ambient	$R_{ hetaJA}$	250	°C/W
Forward Surge Current (Note 4) @ $T_A = 25^{\circ}C$	I _{FSM}	40	А
Operating and Storage Temperature Range	T _J , T _{stg}	-65 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. 10 X 1000 μs, non-repetitive.

2. 1" square copper pad, FR-4 board.

3. FR-4 board, using Littelfuse minimum recommended footprint, as shown in 403AA case outline dimensions spec.

1/2 sine wave (or equivalent square wave), PW = 8.3 ms, duty cycle = 4 pulses per minute maximum.

ELECTRICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Symbol	Parameter					
I _{PP}	Maximum Reverse Peak Pulse Current					
V _C	Clamping Voltage @ I _{PP}					
V _{RWM}	Working Peak Reverse Voltage					
I _R	Maximum Reverse Leakage Current @ V _{RWM}					
V _{BR}	Breakdown Voltage @ I _T					
Ι _Τ	Test Current					
١ _F	Forward Current					
V _F	Forward Voltage @ I _F					



ELECTRICAL CHARACTERISTICS

		Vowe In @	Breakdown Voltage			V _C @ I _{PP} (Note 7)		C Typ	V_F @ I_F (Note 9)		
	Device	(Note 5) V _{RWM}		V _{BR} (Volts) (Note 6) @ I _T			@ I _T	v _c	I _{PP}	(Note 8)	Мах
Device	Marking	Volts	μΑ	Min	Nom	Max	mA	Volts	Amps	pF	v
NSA5.0AFT3G	QA	5.0	400	6.4	6.7	7.0	10	9.2	43.5	2450	3.5

5. A transient suppressor is normally selected according to the working peak reverse voltage (V_{RWM}), which should be equal to or greater than the DC or continuous peak operating voltage level.
V_{BR} measured at pulse test current I_T at an ambient temperature of 25°C.

7. Surge current waveform per Figure 2 and derate per Figure 3.

8. Bias voltage = 0 V, F = 1.0 MHz, $T_J = 25^{\circ}C$.

9. 1/2 sine wave or equivalent, PW = 8.3 ms, non-repetitive, I_F = 30 A.

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RATING AND TYPICAL CHARACTERISTIC CURVES





Figure 5. Steady State Power Derating

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PACKAGE DIMENSIONS

SMA-FL CASE 403AA-01 ISSUE O



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